**Product data sheet** 

# 1. General description

Silicon Carbide Schottky diode in a TO220F-2L plastic package, designed for high frequency switched-mode power supplies.



### 2. Features and benefits

- Highly stable switching performance
- Extremely fast reverse recovery time
- · Superior in efficiency to Silicon Diode alternatives
- · Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant
- Insulated package rated at 2500V RMS

## 3. Applications

- Power factor correction
- Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes	s Values			Unit
Absolute	maximum rating						
$V_{RRM}$	repetitive peak reverse voltage				650		V
$I_{F(AV)}$	average forward current	$δ$ = 0.5; square-wave pulse; $T_h \le 93$ °C; Fig. 1; Fig. 2; Fig. 3		4			А
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics						
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 4 A; T <sub>j</sub> = 25 °C; <u>Fig. 5</u>		-	1.45	1.70	V
		I <sub>F</sub> = 4 A; T <sub>j</sub> = 150 °C; <u>Fig. 5</u>		-	1.80	2.20	V

# 5. Pinning information

**Table 2. Pinning information** 

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		1/ <b>1</b> /1 A
2	А	anode	000	K — A 001aaa020
mb	n.c.	mounting base; isolated		

# 6. Ordering information

### **Table 3. Ordering information**

Type number	Package	Orderable part number	Packing	Small packing	Package	Package
	name		method	quantity	version	issue date
WNSC5D04650X	TO220F-2L	WNSC5D04650X6Q	Tube	50	TO220FN-2L	20-July-2016

# 7. Marking

### **Table 4. Marking codes**

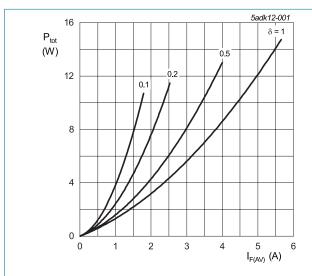
Type number	Marking codes
WNSC5D04650X	WNSC5D 04650X

# 8. Limiting values

#### **Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
$V_{RRM}$	repetitive peak reverse voltage			650	V
$V_{\text{RWM}}$	crest working reverse voltage			650	V
$V_R$	reverse voltage	DC		650	V
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5; square-wave pulse; T <sub>h</sub> ≤ 93 °C; Fig. 1; Fig. 2; Fig. 3		4	А
I <sub>FRM</sub>	repetitive peak forward current	$\delta$ = 0.5; t <sub>p</sub> = 25 μs; T <sub>h</sub> ≤ 93 °C; square-wave pulse		8	А
I <sub>FSM</sub>	non-repetitive peak	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse		24	Α
	forward current	$t_p = 10 \mu s; T_{j(init)} = 25 °C; square-wave pulse$		260	Α
l <sup>2</sup> t	I <sup>2</sup> t for fusing	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse		2.88	A <sup>2</sup> s
T <sub>stg</sub>	storage temperature			-55 to 175	°C
T <sub>j</sub>	junction temperature			-55 to 175	°C



$$\begin{split} & |_{\text{F(AV)}} = |_{\text{F(RMS)}} \times \sqrt{\delta} \\ & |_{\text{O}} = 1.044 \text{ V; R}_{\text{s}} = 0.2758 \text{ }\Omega \\ \end{split}$$
 Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

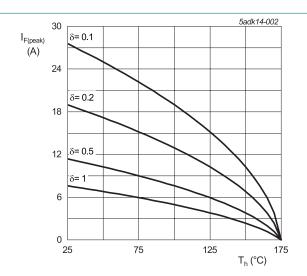
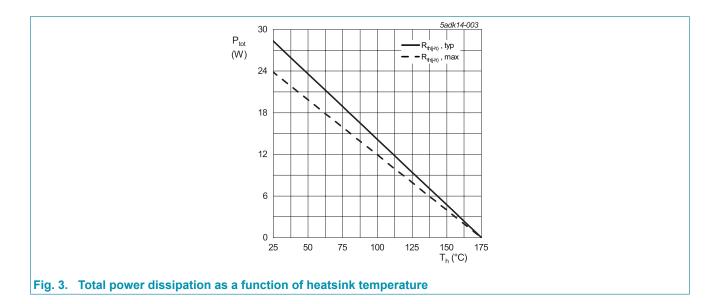


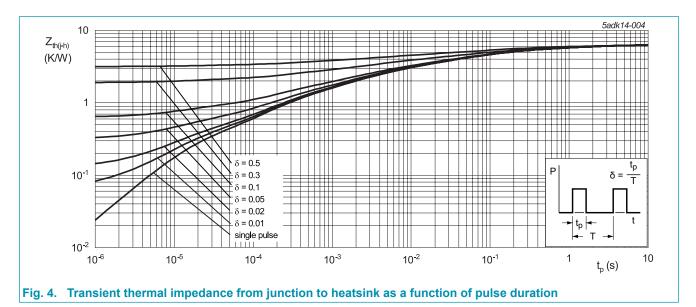
Fig. 2. Current derating as a function of heatsink temperature



### 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
$R_{th(j-h)}$	thermal resistance from junction to heatsink	with heatsink compound; Fig. 4		-	5.3	6.3	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air		-	50	-	K/W



### 10. Isolation characteristics

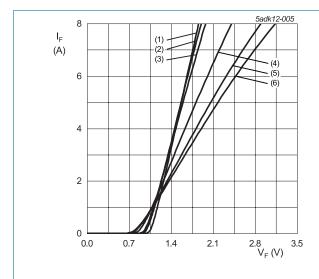
**Table 7. Isolation characteristics** 

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
$V_{\text{isol}(\text{RMS})}$	RMS isolation voltage	from all terminals to external heatsink; sinusoidal waveform; clean and dust free; 50 Hz $\leq$ f $\leq$ 60 Hz; T <sub>h</sub> = 25 °C; RH $\leq$ 65 %		-	-	2500	V

## 11. Characteristics

Table 8 Characteristics

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Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	aracteristics						
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 4 A; T <sub>j</sub> = 25 °C; <u>Fig. 5</u>		-	1.45	1.70	V
		I <sub>F</sub> = 4 A; T <sub>j</sub> = 150 °C; <u>Fig. 5</u>		-	1.80	2.20	V
		I <sub>F</sub> = 4 A; T <sub>j</sub> = 175 °C; <u>Fig. 5</u>		-	2.00	2.30	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 650 V; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>		-	0.2	20	μA
		V <sub>R</sub> = 650 V; T <sub>j</sub> = 175 °C; <u>Fig. 6</u>		-	10	100	μA
Dynamic	characteristics						
$Q_r$	recovered charge	$I_F = 4 \text{ A}$ ; $V_R = 400 \text{ V}$ ; $dI_F/dt = 500 \text{ A/}\mu\text{s}$ ; $T_j = 25 \text{ °C}$ ; Fig. 7		-	6	-	nC
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 1 V; T <sub>j</sub> = 25 °C		-	138	-	pF
		f = 1 MHz; V <sub>R</sub> = 300 V; T <sub>j</sub> = 25 °C		-	17	-	pF
		f = 1 MHz; V <sub>R</sub> = 600 V; T <sub>j</sub> = 25 °C		-	15	-	pF
E <sub>as</sub>	non-repetitive avalanche energy	$I_R = 2.8 \text{ A}; T_{j(init)} = 25 \text{ °C}; L = 5 \text{ mH}$		20	-	-	mJ



 $V_0 = 1.044 \text{ V}; R_s = 0.2758 \Omega$ 

(1) T<sub>i</sub> = -55 °C; typical values

(2) T<sub>i</sub> = 0 °C; typical values

(3) T<sub>i</sub> = 25 °C; typical values

(4) T<sub>j</sub> = 100 °C; typical values (5) T<sub>j</sub> = 150 °C; typical values (6) T<sub>j</sub> = 175 °C; typical values

Fig. 5. Forward current as a function of forward

voltage; typical values

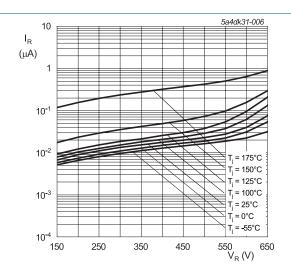
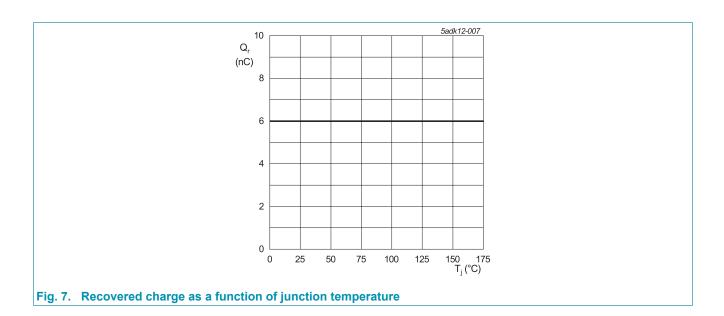
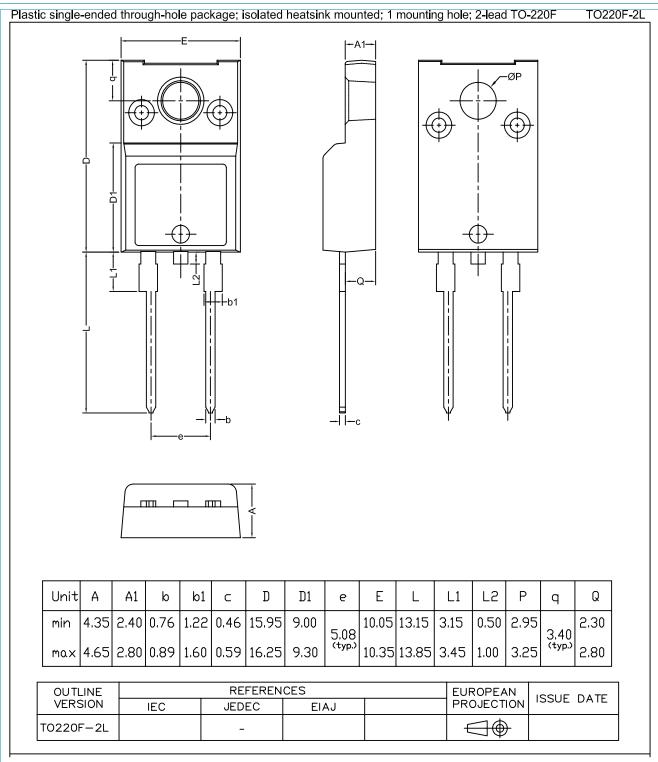


Fig. 6. Reverse leakage current as a function of reverse voltage; typical value



# 12. Package outline



### 13. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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